Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass and metal

Overall Length:

0.340 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.187 inches

Thread Size:

0.112 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

6.8 breakdown voltage, dc

Power Rating Per Characteristic:

10.0 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Thread Series Designator:

Unc

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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